TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSIV)

TK25A10K3

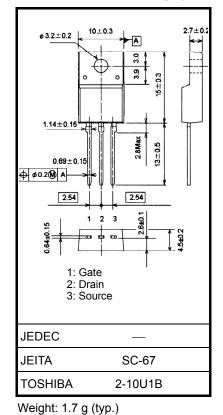
Swiching Regulator Applications

- Low drain-source ON resistance: $RDS(ON) = 31 m\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 50 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A (max) (V_{DS} = 100 \ V)$
- Enhancement-model: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit |
|--|----------------|------------------|------------|------|
| Drain-source voltage | | V _{DSS} | 100 | V |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | V _{DGR} | 100 | V |
| Gate-source voltage | | V _{GSS} | ±20 | V |
| Drain current | DC (Note 1) | ۱ _D | 25 | А |
| | Pulse (Note 1) | I _{DP} | 50 | A |
| Drain power dissipation (Tc = 25° C) | | PD | 25 | W |
| Single pulse avalanche energy (Note 2) | | E _{AS} | 39 | mJ |
| Avalanche current | | I _{AR} | 25 | А |
| Repetitive avalanche energy (Note 3) | | E _{AR} | 1.72 | mJ |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature range | | T _{stg} | –55 to 150 | °C |

Unit: mm



Note: Using continuously under heavy loads (e.g. the application of

high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

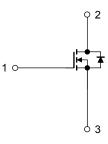
Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: $V_{DD} = 25 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}, \text{ L} = 100 \text{ }\mu\text{H}, \text{ R}_{G} = 25 \Omega, \text{ I}_{AR} = 25 \text{ A}$

Note 3: Repetitive rating; pulse width limited by maximum channel temperature.

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|------|--------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 5.0 | °C / W |
| Thermal resistance, channel to ambient | R _{th (ch−a)} | 62.5 | °C / W |



This transistor is an electrostatic sensitive device. Please handle with caution.

Start of commercial production 2009-06

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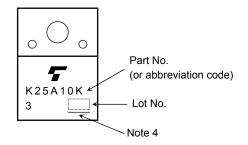
Electrical Characteristics (Ta = 25°C)

| Cha | racteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--|---------------|----------------------|--|-----|------|------|------|
| Gate leakage cur | rent | I _{GSS} | $V_{GS}=\pm 20~V,~V_{DS}=0~V$ | _ | | ±100 | nA |
| Drain cut-OFF cu | ırrent | I _{DSS} | $V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | _ | _ | 10 | μA |
| Drain-source breakdown voltage | | V (BR) DSS | $I_D = 10$ mA, $V_{GS} = 0$ V | 100 | | | v |
| | | V (BR) DSX | $I_D=10\ mA,\ V_{GS}=-20\ V$ | 65 | | | |
| Gate threshold ve | oltage | V _{th} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$ | 2.0 | | 4.0 | V |
| Drain-source ON | resistance | R _{DS (ON)} | $V_{GS} = 10 \text{ V}, I_D = 12 \text{ A}$ | _ | 31 | 40 | mΩ |
| Forward transfer | admittance | Y _{fs} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 12 \text{ A}$ | 25 | 50 | | S |
| Input capacitance Reverse transfer capacitance | | C _{iss} | $V_{DS} = 10V, V_{GS} = 0 V, f = 1 MHz$ | _ | 1580 | | pF |
| | | C _{rss} | | | 135 | _ | |
| Output capacitance | | C _{oss} | | | 200 | | |
| Switching time | Rise time | tr | V_{GS} $0 V$ U_{DUT} $0 V$ U_{DUT} $0 V$ U_{DUT} $0 V$ $V_{DD} \approx 50 V$ $0 V$ $0 V$ $0 V$ $0 V$ V_{DUT} $0 V$ $V_{DD} \approx 50 V$ $0 V$ 0 | _ | 13 | _ | |
| | Turn-on time | t _{on} | | | 25 | | - ns |
| | Fall time | t _f | | | 8 | _ | |
| | Turn-off time | t _{off} | | | 37 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | $V_{DD}\approx 80$ V, V_{GS} = 10 V, I_{D} = 25 A | | 34 | | nC |
| Gate-source charge | | Q _{gs} | | _ | 7 | | |
| Gate-drain ("miller") charge | | Q _{gd} | | _ | 13 | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | — | _ | _ | 25 | А |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 50 | А |
| Forward voltage (diode) | V _{DSF} | $I_{DR} = 25 \text{ A}, V_{GS} = 0 \text{ V}$ | _ | _ | -1.4 | V |
| Reverse recovery time | t _{rr} | $I_{DR} = 25 \text{ A}, \text{ V}_{GS} = 0 \text{ V},$ | _ | 57 | _ | ns |
| Reverse recovery charge | Q _{rr} | dl _{DR} /dt = 50 A/μs | _ | 61 | _ | nC |

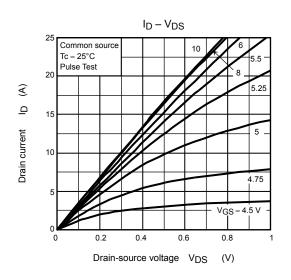
Marking

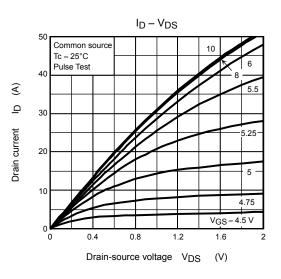


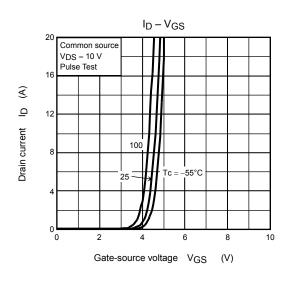
Note 4: A line under a Lot No. identifies the indication of product Labels Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

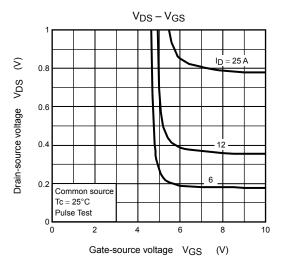
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

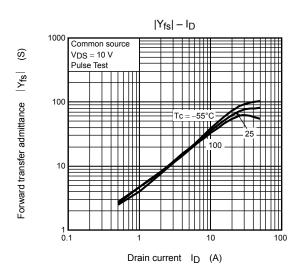
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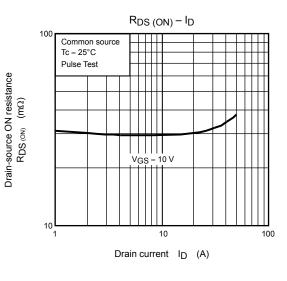




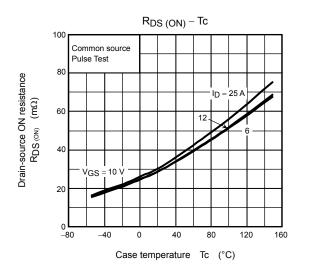


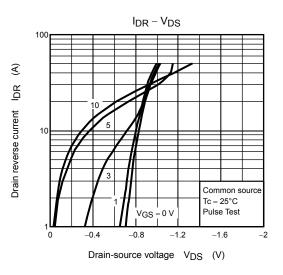


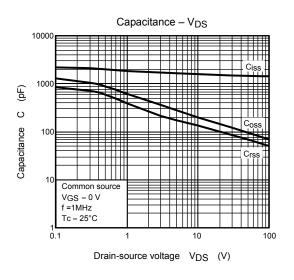


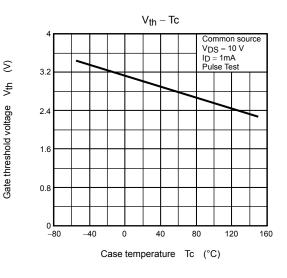


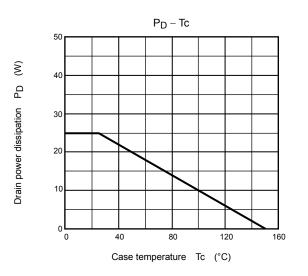
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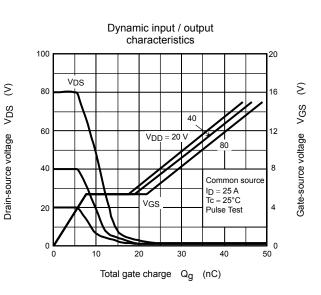


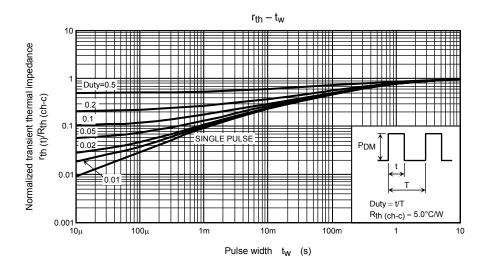




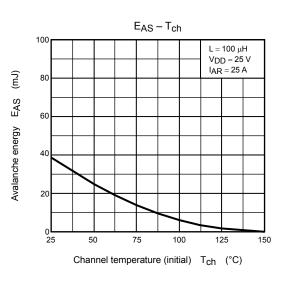


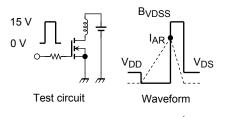






SAFE OPERATING AREA 100 T 100 µs * ID max (pulse) 1 m 10 E Drain current I_D ⋕ ------Ш * Single pulse Tc=25°C Curves must be derated linearly with increase in temperature. V_{DSS} max 0.1 **L** 0.1 10 1 100 1000 Drain-source voltage V_{DS} (V)





| $R_G = 25 \Omega$ | $E_{AS} = \frac{1}{2} \cdot L \cdot l^2 \cdot ($ | BVDSS | |
|----------------------------|--|-----------|---|
| $V_{DD}=25~V,~L=100~\mu H$ | -A3 2 | BVDSS-VDD |) |

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